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Correction

Nonlocal fractional MGT-non-Fourier photothermal model with spatial and temporal nonlocality for controlling the behavior of semiconductor materials with spherical cavities

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A correction on

Nonlocal fractional MGT-non-Fourier photothermal model with spatial and temporal nonlocality for controlling the behavior of semiconductor materials with spherical cavities by Mofareh Alhazmi and Ahmed E. Abouelregal. AIMS Mathematics, 2025, 10(3): 7559–7590.

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The author would like to make the following correction to the published paper [1].

The second affiliation, Department of Mathematics, Faculty of Science, Mansoura University, Mansoura 35516, Egypt, must be removed. The paper should only include the first affiliation: Mathematics Department, College of Science, Jouf University, P.O. Box 2014, Sakaka, Saudi Arabia.

The changes have no material impact on the conclusion of this article. The original manuscript will be updated [1]. We sincerely apologize for any inconvenience this change may cause to our readers.

Conflict of interest

The authors declare there is no conflict of interest.

References

1. M. Alhazmi, A. E. Abouelregal, Nonlocal fractional MGT-non-Fourier photothermal model with spatial and temporal nonlocality for controlling the behavior of semiconductor materials with spherical cavities, *AIMS Math.*, **10** (2025), 7559–7590. https://doi.org/10.3934/math.2025348



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